

(19) World Intellectual Property
Organization
International Bureau



(43) International Publication Date
7 April 2005 (07.04.2005)

PCT

(10) International Publication Number
WO 2005/031891 A1

(51) International Patent Classification⁷: H01L 51/30,
C08F 12/32, 26/12, C08J 5/20, H01L 51/20

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(21) International Application Number:

PCT/CA2004/001755

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(22) International Filing Date:

29 September 2004 (29.09.2004)

(81) Designated States (unless otherwise indicated, for every kind of national protection available): AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, EG, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NA, NI, NO, NZ, OM, PG, PH, PL, PT, RO, RU, SC, SD, SE, SG, SK, SL, SY, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, YU, ZA, ZM, ZW.

(25) Filing Language:

English

(26) Publication Language:

English

(30) Priority Data:

60/507,506 2 October 2003 (02.10.2003) US

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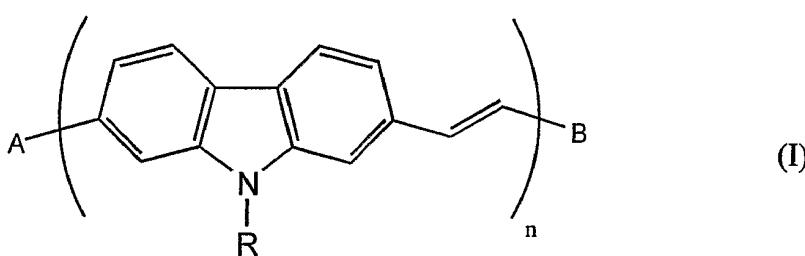
(84) Designated States (unless otherwise indicated, for every kind of regional protection available): ARIPO (BW, GH, GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW), Eurasian (AM, AZ, BY, KG, KZ, MD, RU, TJ, TM), European (AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IT, LU, MC, NL, PL, PT, RO, SE, SI, SK, TR), OAPI (BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG).

(72) Inventors; and

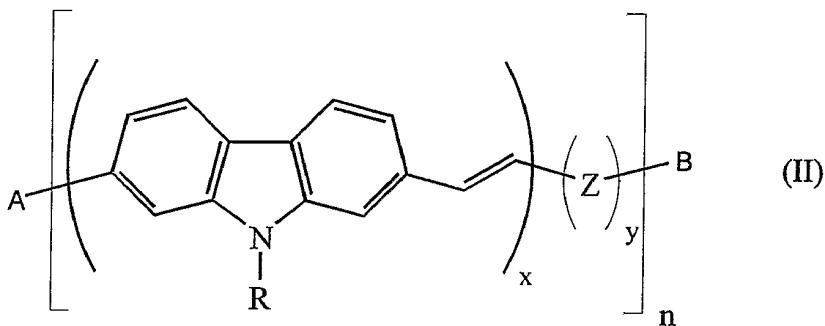
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(54) Title: 2,7-CARBAZOLENEVINYLENE DERIVATIVES AS NOVEL MATERIALS IN PRODUCING ORGANIC BASED ELECTRONIC DEVICES



(57) Abstract: Organic Field Effect Transistor (OFET), an Organic Light Emitting Diode (OLED), an and an Organic Photovoltaic Cell (OPC) including as active material a conjugated oligomeric or polymeric 2,7-carbazolenevinylene derivative described by the formula (I) or (II). Such OFETs, OLEDs and OPCs have improved devices properties and efficiencies.



**Published:**

- *with international search report*
- *before the expiration of the time limit for amending the claims and to be republished in the event of receipt of amendments*

For two-letter codes and other abbreviations, refer to the "Guidance Notes on Codes and Abbreviations" appearing at the beginning of each regular issue of the PCT Gazette.

2,7-CARBAZOLENEVINYLENE DERIVATIVES AS NOVEL MATERIALS IN PRODUCING ORGANIC BASED ELECTRONIC DEVICES

This application claims the benefit of U.S. Provisional Application 60/507,506
5 filed October 1, 2003.

Field of the Invention

The present invention relates to the field of electronic and optoelectronic devices, and more particularly to organic based semi-conductor devices such as Organic
10 Field Effect Transistors (OFETs), Organic Light Emitting Diodes (OLEDs) and Organic Photovoltaic Cells (OPCs).

Background

Organic conjugated oligomers and polymers are materials that possess a
15 delocalized pi-electron system along their backbone. These organic materials are subject to important investigations from both academic and industrial laboratories due to their great potential for applications in electronic and optoelectronic devices, such as field effect transistors (OFETs), light emitting diodes (OLEDs) and photovoltaic cells (OPCs). The economical advantages of using
20 organic over inorganic semi-conducting materials in devices include, low cost of synthesis, ease of processing and the extensive tunability range of their optical and electrical properties through chemical modifications.

The vast majority of microelectronic devices are currently based on inorganic
25 semi-conductor materials such as crystalline silicon. For large area devices including flat-panel displays and smart cards, where the use of crystalline silicon is limited by the size of the single crystals, amorphous and polycrystalline silicon are currently used. However, the relatively high temperatures needed in their fabrication process prevent their utilization with plastic substrates. On the other

hand organic materials can be processed at or near room temperature by solution-processing or thermal evaporation on polymeric substrates. Organic-based devices such as OFETs are gaining interest as their performance has increased up to a point that they now compete with their inorganic counterparts.

5 In the short term, it is recognized that organic semi-conductor materials could be used in the production of low-resolution components, such as identification tags, smart cards and pixel drivers for displays. Up to now, only pentacene and regioregular polythiophenes have demonstrated the required performances, but the former is difficult to process and the later is easily oxidized in air.

10

Additionally, it has long been felt that a technically viable emissive display technology could compete with the currently dominating technology of liquid crystal displays (LCDs) and OLEDs are today considered to be in the best position to do just that. Current LCDs present limitations such as low efficiency,

15 poor vision angle, and speed and temperature range limitations. OLEDs, however, demonstrate particular promise for displays as they can be tuned to any colour, operate at relatively low voltages with high efficiency and have excellent visual properties. A lot of work is going on in chemistry laboratories to find materials with high luminous quantum efficiency, good colour purity and
20 great stability for the application to OLED displays. While some materials meet or exceed some of the requirements for commercial displays, to date none meets them all.

Furthermore, the need to develop renewable energy sources continues to
25 stimulate new approaches to the conversion of solar energy into electrical energy through the production of photovoltaic devices. Although inorganic semi-conductors such as silicon, amorphous silicon, gallium arsenide and sulfide salts, have been the primary focus of commercial applications, the photosensitivity and the photovoltaic effects in devices made with conjugated oligomeric or polymeric

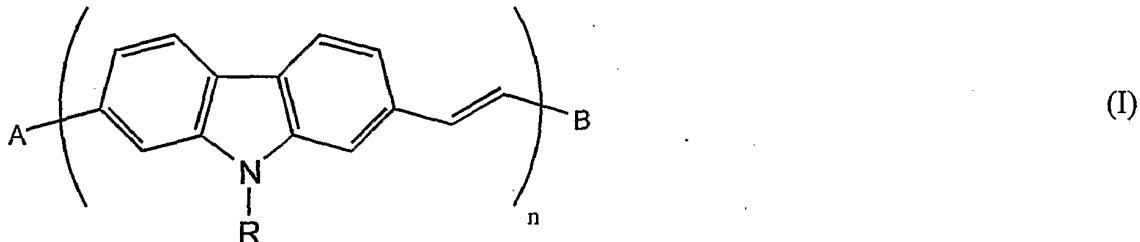
organic materials have also been explored and have shown excellent results. The main advantage of using organic materials in photovoltaic devices is the low-cost of fabrication in large sizes and in desired configurations. As an example, the use of semi-transparent organic thin film on the roof area or between insulating 5 windows could be employed as power generation in new and existing buildings.

Intense research is going on at the chemistry level to find a class of organic materials that could be used in OFETs as well as in OLEDs and OPCs. This new 10 class of organic materials should be easy to synthesis at a low cost and should be easy to tune over a wide range of electrical and optical properties through chemical modifications to meet the entire required criteria for commercialization of OFETs, OLEDs and OPCs.

Summary of The Invention

15 According to the present invention there are provided organic-based electronic devices and methods of preparing such devices. These devices include Organic Field Effect Transistors (OFETs), Organic Light Emitting Diodes (OLEDs), and Organic Photovoltaic Cells (OPCs) and have as their active material a conjugated 2,7-carbazolenevinylene derivative of the formula (I):

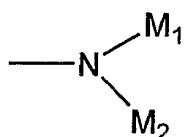
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wherein n is an integer ≥ 3 , R represents a substituent that is a hydrogen, or linear or branched alkyl group containing 1 to 20 carbon atoms, linear or 25 branched alkoxy group containing 1 to 20 carbon atoms, poly (ethyleneoxy),

cyano, aryl group, amide group or benzoyl group, and A, B are any type of end-cap groups.

For example, A and B end-cap groups can be selected from hydrogen, linear or
5 branched alkyl group containing 1 to 20 carbon atoms, linear or branched alkoxy group containing 1 to 20 carbon atoms, cyano, fluoro, chloro, bromo, iodo, monovalent aromatic group, e.g. a phenyl, a naphthyl, and a anthryl group, or monovalent aromatic complex ring group having one nitrogen atom as a hetero-atom, e.g. a pyrropyl group, a pyridyl group, quinolyl group and a carbazolyl
10 group. These aryl groups (aromatic groups) and aromatic complex ring groups may have, or need not have substituants. For example, substituants may be selected from a linear or branched alkyl group containing 1 to 20 carbon atoms, linear or branched alkoxy group containing 1 to 20 carbon atoms, acyl group, benzyl group, aryloxy group, alkoxy-carbonyl group, acyloxy group, acylamino
15 group, halogen group, carboxyl group, hydroxy group, aminocarbonyl group, aryloxycarbonyl group, aryl group, and further amino group represented by the general formula:



20

wherein M₁ and M₂ are each an hydrogen atom, or linear or branched alkyl group, acyl group such as an aldehyde group, a formyl group, an acetyl group and a propyonyl group, aryl group and the like; M₁ and M₂ may be the same or different, and they may combine with each other to form a saturated five-
25 membered ring or a saturated six-membered ring (these rings may be with or without a substituant), and may combine with the substituants on A and B to

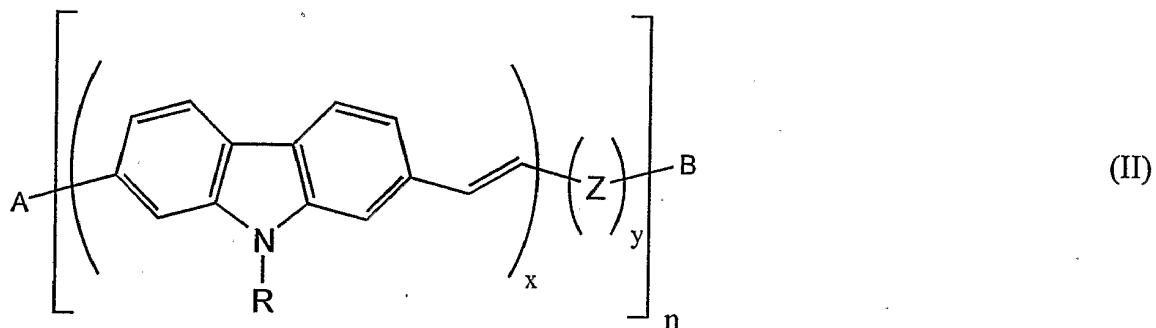
form a saturated five-membered ring or a saturated six-membered ring (these rings may be with or without a substituant).

In general formula (I), A and B may be the same or different, and the substituants

5 on A and B may combine with each other to form a saturated five-membered ring or a saturated six-membered ring (these rings may be with or without a substituant).

2,7-carbazolenevinylene monomers can also be alternated with other monomers

10 to form oligomeric or polymeric materials according to the general formula (II):



wherein n is an integer ≥ 3 , R represents a substituant that is a hydrogen, or

15 linear or branched alkyl group containing 1 to 20 carbon atoms, linear or branched alkoxy group containing 1 to 20 carbon atoms, poly (ethyleneoxy), cyano, aryl group, amide group or benzoyl group, x is an integer between 1 to 1000, y is an integer between 0 to 1000, Z is any type of comonomer, and A, B are any type of end-cap groups.

20

The conjugated oligomeric and polymeric 2,7-carbazolenevinylene derivatives comprise repeating or alternating units of the above formula (II). For example, the comonomers can be selected from ethylene, acetylene, C₆-C₂₂

mononuclear/polynuclear aromatic, C₂-C₁₀ mononuclear/polynuclear heterocyclic groups and tertiary arylamines.

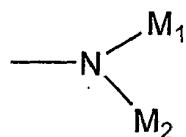
Examples of mononuclear/polynuclear aromatic group are: phenylene, fluorene, 5 naphthalene, anthracene, tetracene, pyrene, perylene, rubrene, phenanthrene, naphthylene, acenaphthene, fluoranthene and chrysene. Examples of mononuclear/polynuclear heterocyclic internal groups include 5-member heterocyclic groups such as furan, thiophene, pyrrole, oxazole, isooxazole, oxadiazoles, thiazole, isothiazole, imidazole, thiadiazole and pyrazole; 6-member 10 heterocyclic groups such as pyridine, pyridazine, pyrimidine, pyrazine, triazine and tetrazine; benzo-fused ring systems such as benzooxazole, benzothiazole, benzimidazole, quinoline, isoquinoline, cinnoline, quinazoline, quinoxaline, phthalazine, benzothiadiazole and benzotriazine; polynuclear fused condensed ring systems such as phenazine, phenanthridine, acridine and diphenylene 15 oxide. Examples of tertiary arylamine groups include triphenylamine, N,N'-diphenylbenzidine, N,N'-diphenyl-1,4-phenylenediamine and diphenylnaphthylamine. Olefinic, aromatic, heterocycle and tertiary arylamines groups may be substituted optionally with one or more substituents. Examples of substituents include C₁-C₂₀ linear or branched alkyl group, C₁-C₂₀ linear or 20 branched alkoxy group, cyano, fluoro, chloro, bromo, iodo, C₁-C₂₀ linear or branched alkyloxycarbonyl, C₁-C₂₀ linear or branched aryloxycarbonyl and poly(alkyleneoxy). Such substituents may be selected to improve the solubility or processing characteristics of the materials.

25 For example, A and B end-cap groups can be selected from hydrogen, linear or branched alkyl group containing 1 to 20 carbon atoms, linear or branched alkoxy group containing 1 to 20 carbon atoms, cyano, fluoro, chloro, bromo, iodo, monovalent aromatic group, e.g. a phenyl, a naphthyl, and a anthryl group, or monovalent aromatic complex ring group having one nitrogen atom as a hetero-

atom, e.g. a pyrropyl group, a pyridyl group, quinolyl group and a carbazolyl group. These aryl groups (aromatic groups) and aromatic complex ring groups may have, or need not have substituents. For example, substituents may be selected from a linear or branched alkyl group containing 1 to 20 carbon atoms,

5 linear or branched alkoxy group containing 1 to 20 carbon atoms, acyl group, benzyl group, aryloxy group, alkoxy-carbonyl group, acyloxy group, acylamino group, halogen group, carboxyl group, hydroxy group, aminocarbonyl group, aryloxycarbonyl group, aryl group, and further amino group represented by the general formula:

10



wherein M₁ and M₂ are each an hydrogen atom, or linear or branched alkyl group, acyl group such as an aldehyde group, a formyl group, an acetyl group

15 and a propyonyl group, aryl group and the like; M₁ and M₂ may be the same or different, and they may combine with each other to form a saturated five-membered ring or a saturated six-membered ring (these rings may be with or without a substituant), and may combine with the substituants on A and B to form a saturated five-membered ring or a saturated six-membered ring (these rings may be with or without a substituant).

20

In general formula (II), A and B may be the same or different, and the substituants on A and B may combine with each other to form a saturated five-membered ring or a saturated six-membered ring (these rings may be with or 25 without a substituant).

Oligomeric and polymeric carbazole derivative materials are a well-known class of materials. It has now been discovered how to synthesize highly conjugated poly (N-alkyl-2,7-carbazole) and a patent application entitled "Conjugated Polycarbazole Derivatives and Process for the synthesis thereof" on the method

5 of synthesis was filed October 31, 2001 under serial number 10/003,774.

Moreover, it has now been discovered that highly conjugated poly (N-alkyl-2,7-carbazole) can be used as active material in OLEDs and a patent application entitled "The Use of Conjugated Polycarbazole Derivatives in Organic Light Emitting Diodes" has been accorded (US patent US6630254). The same authors of

10 the former patent have discovered how to synthesized conjugated 2,7-

carbazolenevinylene oligomeric and polymeric materials and a patent application entitled "2,7-carbazolenevinylene: A New Class of Organic Materials for Optical and Electrical Applications" on their method of synthesis was filed August 15, 2003 under serial number 60/495,113. The present invention provides, interalia, use of conjugated

15 oligomeric and polymeric 2,7-carbazolenevinylene derivatives as the active material in OFETs, OLEDs, and OPCs.

2,7-carbazolenevinylene compounds can be used in OFETs as the active p-type semi-conductor or n-type semi-conductor where holes or electrons are the

20 majority carriers respectively, depending of the end-caps and side groups used.

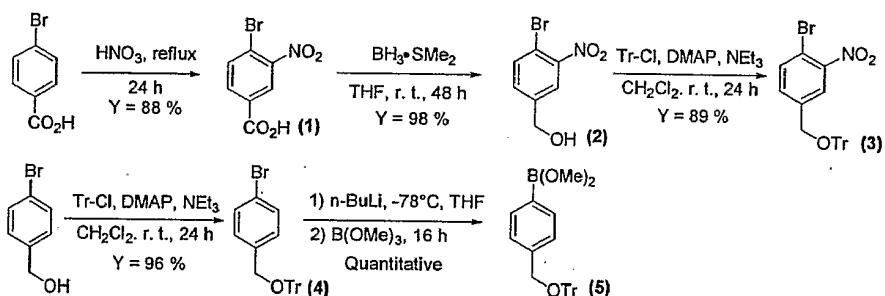
2,7-carbazolenevinylene compounds can be used in OLEDs as emitter, hole transport layers, electron transport layers or any combination of those roles depending of the end-caps and side groups used. They can be used either pure or blended or doped with other hole or electron transport materials. They can 25 also be used in multilayer arrangements to promote confinement or as an alternative to doping.

2,7-carbazolenevinylene compounds can be used in OPCs as absorption layers, free carrier generation layers, hole transport layers, electron transport layers or any combination of those roles depending of the end-caps and side groups used. They can be used either pure or blended or doped with other materials. They can also be used in multilayer arrangements to promote charge transfer process or as an alternative to doping.

Conjugated oligomeric and polymeric 2,7-carbazolenevinylene derivatives can be synthesized by the following route:

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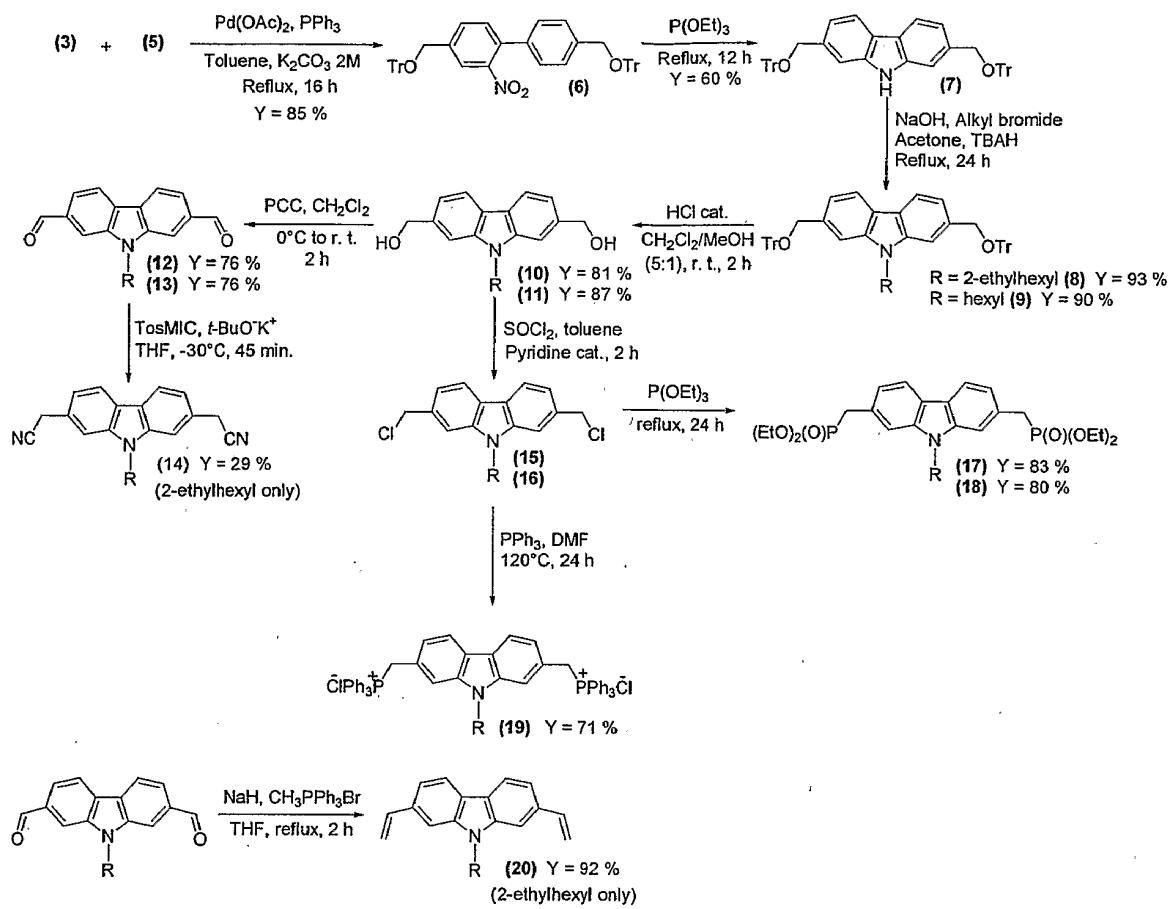
Scheme 1: Synthetic Route to 2,7-difunctionalized carbazole



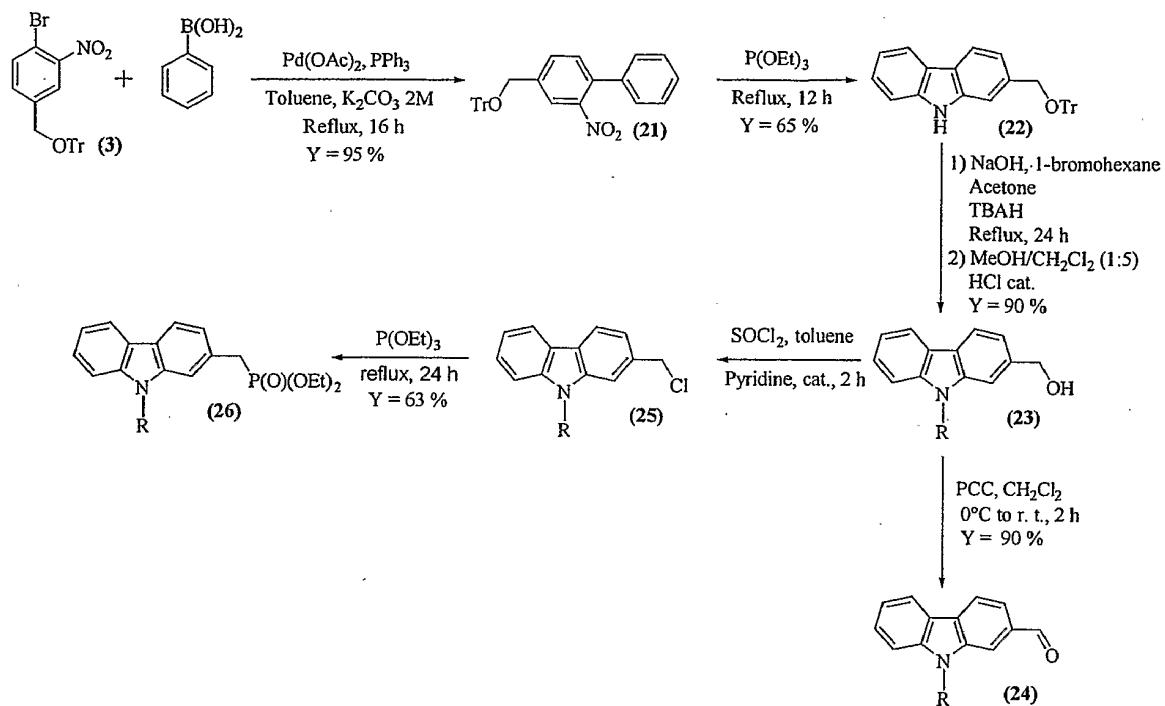
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Scheme 2: Synthetic Route to 2-functionnalized carbazole

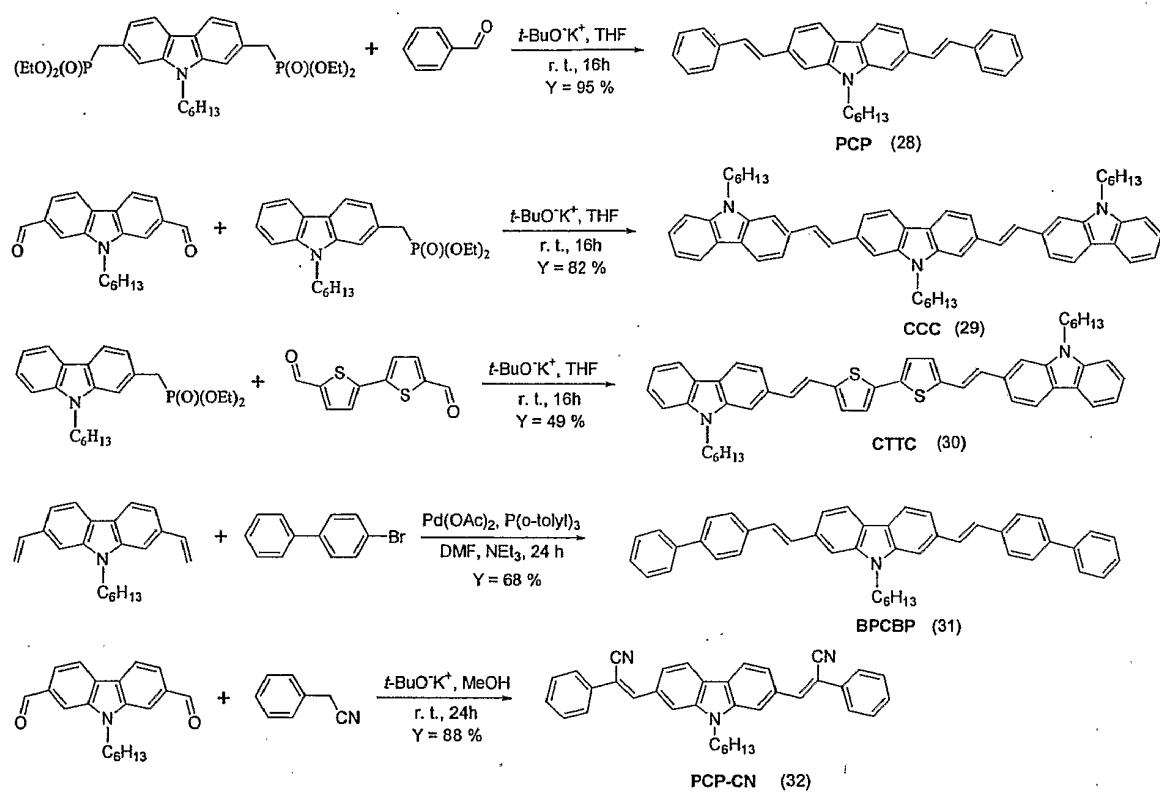


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Scheme 3: Synthetic Route to 2,7-carbazolenevinylene oligomers



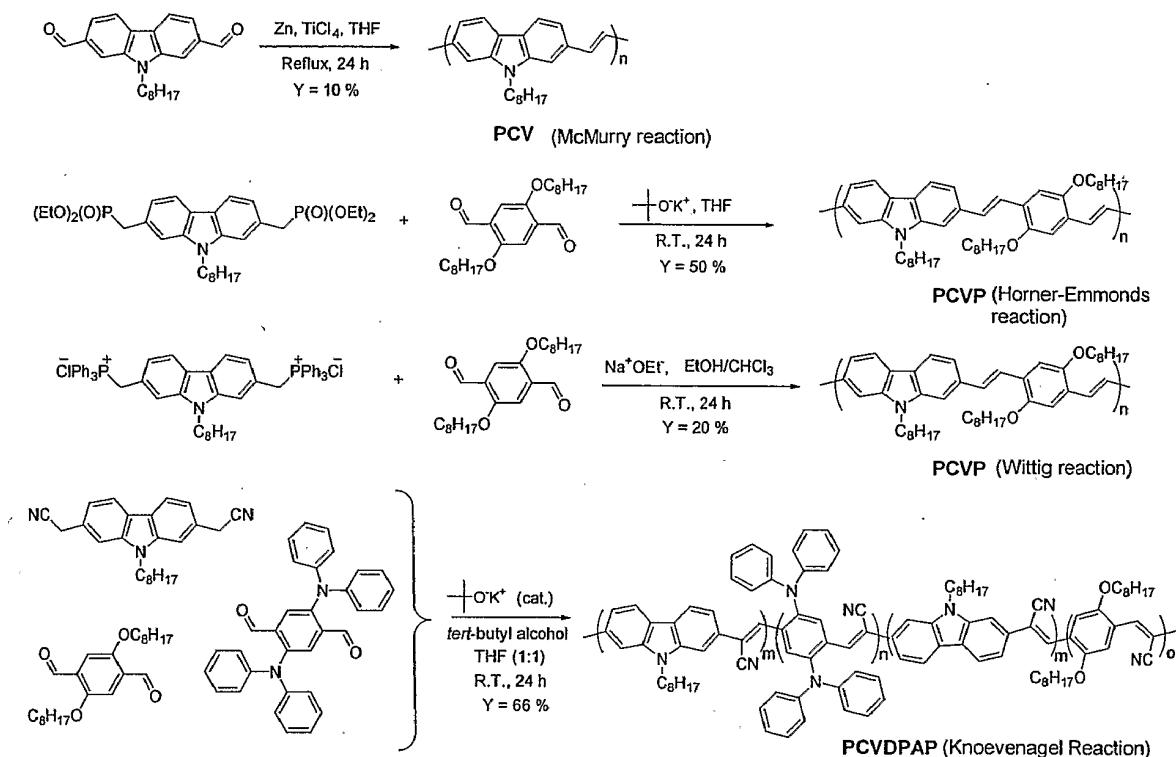
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Scheme 4: Synthetic Route to 2,7-carbazolenevinylene polymers



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Brief Description of the Drawings

The invention will now be described in more details, by way of non-limiting example only, with reference to the accompanying drawings, in which: -

10 Figure 1 shows a prior art small-molecule field-effect transistor.

Figure 2 shows a prior art polymer field-effect transistor.

Figure 3 shows a prior art small-molecule light-emitting diode.

15

Figure 4 shows a prior art polymer light-emitting diode.

Figure 5 shows a prior art small-molecule photovoltaic cell.

Figure 6 shows a prior art polymer photovoltaic cell.

- 5 Figures 7a and 7b show an embodiment of the present invention wherein an OFET is formed using RCPCR 1,4-bis(vinylene-(N-methyl-7-hexyl-2-carbazole))phenylene thin film as the active semi-conductor in the top contact and bottom contact geometry respectively;
- 10 Figure 8 shows the current-voltage characteristics of the embodiment of the transistor shown in Figure 7a (the top contact geometry).
- 15 Figure 9a, 9b and 9c show an embodiment of the present invention wherein an OFET is formed using CPC 1,4-bis(vinylene-(N-hexyl-2-carbazole))phenylene thin film as the active semi-conductor in the top contact geometry using self-assembling monolayer (SAM) chemically modified electrodes with hexamethyldisilazane (HMDS), octyltrichlorosilane (OTS) and octadecyltrichlorosilane (ODS) respectively.
- 20 Figure 10 shows the current-voltage characteristics of the embodiment of the transistor shown in Figure 9a (the top contact geometry with HMDS chemically modified electrodes).
- 25 Figure 11 shows the transistors performances (μ ; mobility and I_{on}/I_{off} ; current ratio) as a function of the temperature of the substrate during CPC thin film deposition depending of the type of electrode used.

Figure 12 shows an embodiment of the invention where an OLED is formed using a PCVDPAP [Poly (N-(2-ethylhexyl-2,7-carbazolenecyanovinylene-co-2,5-

bis(diphenylamine)-1,4-phenylenecyanovinylene-co-2,5-dioctyloxy-1,4-phenylenecyanovinylene] thin film as emitter. The diode consists of an Indium Tin Oxide transparent conductive anode on a glass substrate, PCVDPAP as the emitter and a Ca cathode;

5

Figure 13 shows the electroluminescence spectrum of the diode illustrated in Figure 12;

10 Figure 14 shows the current-voltage (curve 1) and luminescence-voltage (curve 2) characteristics of the diode shown in Figure 12;

15 Figure 15 shows an embodiment of the invention where an OLED is formed using a PCCVP [Poly (N-(2-ethylhexyl)-2,7-carbazolenecyanovinylene-*alt*-2,5-dioctyloxy-1,4-phenylenevinylene] thin film as the emitter. The diode consists of an Indium Tin Oxide transparent conductive anode on a glass substrate, a thin PEDOT-PSS [Poly (ethylene dioxythiophene: polystyrene sulfonate)] layer to promote hole injection, PCCVP as the emitter, Bu-PBD (2-(4-biphenyl)-5-(4-tert-butylphenyl)-1,3,4-oxadiazole) as the electron transport layer, a thin LiF layer to promote electron injection and an Al cathode;

20

Figure 16 shows the electroluminescence spectrum of the embodiment of the diode illustrated in Figure 15;

25 Figure 17 shows the current-voltage (curve 1) and luminescence-voltage (curve 2) characteristics of the diode illustrated in Figure 15;

Figure 18 shows an embodiment of the invention where an OPC is formed using PCVDPATA [Poly (N-(2-ethylhexyl-2,7-carbazolenevinylene-co-2,5-bis(diphenylamine)-1,4-phenylenevinylene-co-((4-(2-ethylhexyloxy)-phenyl)-bis-

(4'-phenylene)amine)] mixed with PTD [N,N'-Bis(2,6-dimethylphenyl)-3,4,9,10-perylenetetracarboxylic diimide] as the absorbing and the transporting layer. The photovoltaic cell consists of an Indium Tin Oxide transparent conductive anode on a glass substrate, PCVDPATA: PTD (20:80) as the absorbing layer and an Al cathode;

Figure 19 shows the current-voltage characteristics in dark and under illumination of the embodiment of the photovoltaic cell shown in Figure 18.

10 Figure 20 shows an embodiment of the invention where an OPC is formed using PPCVT [Poly (N-(4-hexyloxyphenyl)-2,7-carbazolenevinylene-alt-(3-hexyl-2,5-thiophenevinylene))] mixed with PCBM [6,6-phenyl-C61 butyric acid methyl ester] as the absorbing and the transporting layer. The photovoltaic cell consists of an Indium Tin Oxide transparent conductive anode on a glass substrate, 15 PPCVT: PCBM (20:80) as the absorbing layer and an Al cathode; and

Figure 21 shows the current-voltage characteristics in dark and under illumination of the embodiment of the photovoltaic cell shown in Figure 20.

20

Detailed Description of the Invention

Figures 1 through 6 illustrate electronic and opto-electronic devices according to the prior art. The device shown in Figure 1 consists of a n-type silicon wafer 25 covered with a thermally grown SiO₂ film used as substrate, two gold electrodes (source and drain) on top of the substrate, a third electrode (gate) on the back side of the substrate, a thin (NiPc) nickel phthalocyanine layer, and a thin (ScPc) scandium phthalocyanine layer. When a sufficiently high negative voltage is applied to the gate, an inversion layer forms at the insulator/semi-conductor

interface and positive charges are created. Varying the applied voltage at the gate, the negative current between the source and drain through the diphthalocyanine layer is modulated.

- 5 The device shown in Figure 2 consists of a n-type silicon wafer covered with a thermally grown SiO_2 film used as substrate, two gold electrodes (source and drain) on top of the substrate, a third gallium-indium electrode (gate) on the back side of the substrate, and a thin PT (polythiophene) layer. When a sufficiently high negative voltage is applied to the gate, an inversion layer forms at the
- 10 insulator/semi-conductor interface and positive charges are created. By varying the applied voltage at the gate, the negative current between the source and drain through the PT layer is modulated.

The device shown in Figure 3 consists of an Indium Tin Oxide transparent anode on a glass substrate, an aromatic diamine as the hole transport layer, an AlQ_3 (8-hydroxyquinoline aluminum) electron transport and emitter layer, and an Mg:Ag alloy cathode. When a sufficiently positive voltage is applied between the anode and the cathode, holes are injected from the anode, electrons are injected from the cathode and they recombine radiatively in the AlQ_3 emissive layer, producing light that is seen through the transparent anode and hole transport layer.

The device shown in Figure 4 consists of an Indium Tin Oxide transparent anode on a glass substrate, a thin PPV (poly(p-phenylenevinylene)) layer, and an Al cathode. When a sufficiently high positive voltage is applied between the anode and the cathode, holes are injected from the anode, electrons are injected from the cathode and they recombine radiatively in the PPV emissive layer, producing light that is seen through the transparent anode.

The device shown in Figure 5 consists of an Indium Tin Oxide transparent anode on a glass substrate, a thin CuPc (copper phtalocyanine) layer, a thin PV (perylene tetracarboxylic) layer, and an Ag cathode. Under illumination through the transparent Indium Tin Oxide anode, charges are produced. When a 5 sufficiently positive voltage is applied between the anode and the cathode, the photogenerated charges are transported and transferred to the electrodes.

The device shown in Figure 6 consists of an Indium Tin Oxide transparent anode on a glass substrate, a thin PPV (poly(p-phenylenevinylene)) layer, and an Al 10 cathode. Under illumination through the transparent Indium Tin Oxide anode, charges are produced in PPV. When a sufficiently positive voltage is applied between the anode and the cathode, the photogenerated charges are transported and transferred to the electrodes.

15 Examples of organic-based devices prepared in accordance with the present invention will now be described.

FIRST EXAMPLE

20 In a first embodiment of the present invention as shown in Figure 7, an OFET was fabricated in the top contact geometry consisting of; a p-type silicon wafer covered with a thermally grown SiO₂ film used as a substrate, a thin RCPCR semi-conductor layer, a source and drain gold electrode on top of the organic semi-conductor layer, and a gate electrode on the back side of the substrate. 25 Prior to use, each substrate (15 x 15 mm²) is cleaned sequentially with acetone, ultrasonicated isopropanol at 80°C, and UV/ozone cleaner for 10 min. In order, the organic semi-conductor RCPCR and gold are deposited by thermal evaporation at a pressure of 1 x 10⁻⁷ torr at a substrate temperature of 25°C for RCPCR and 25°C for gold. The gold source and drain electrodes are deposited

on top of the organic semi-conductor through a shadow mask forming a top contact geometry with a channel length of 40 μm and a channel width of 1 μm . An electrical wired bonded on the backside of the p-doped silicon wafer forms the gate electrode.

5

The field effect transistor produces the current-voltage characteristics shown in Figure 8. It is shown that RCPCR forms a typical p-channel transistor operating in two different modes, which are the linear regime where the current follows Ohm's law at low source-drain voltage and the saturation regime as the source-drain voltage increase. In the conditions described above, RCPCR shows a mobility of $1.0 \times 10^{-4} \text{ cm}^2/\text{V}$ and $I_{\text{on}}/I_{\text{off}}$ ratio of 10^4 .

10

SECOND EXAMPLE

15

In a second embodiment of the present invention as shown in Figure 9, an OFET was fabricated in the top contact geometry consisting of; a p-type silicon wafer covered with a thermally grown SiO_2 film used as a substrate, a thin CPC semi-conductor layer, a source and drain gold electrode on top of the organic semi-conductor layer, and a gate electrode on the back side of the substrate. Prior to use, each substrate ($15 \times 15 \text{ mm}^2$) is cleaned sequentially with acetone, ultrasonicated isopropanol at 80°C , and UV/ozone cleaner for 10 min. Then, the substrate was treated sequentially in a $\text{NH}_4\text{OH}/\text{H}_2\text{O}_2/\text{H}_2\text{O}$ (2:2:100) solution for 15 min, H_2O for 1 min, $\text{HCl}/\text{H}_2\text{O}_2/\text{H}_2\text{O}$ (2:2:100) solution for 15 min, H_2O for 1 min, dried with N_2 and put in the UV/ozone cleaner for 1 h. Then, the surface of the substrate was treated with hexamethyldisilazane (HMDS) on a vapor prime system at 150°C and 30 mmHg for 2 h prior to evaporation. In order, the organic semi-conductor CPC and gold are deposited by thermal evaporation at a pressure of 1×10^{-7} torr at a substrate temperature of 75°C and 25°C for gold. The

gold source and drain electrodes are deposited on top of the organic semiconductor through a shadow mask forming a top contact geometry with a channel length of 58 μm and a channel width of 1 μm . An electrical wire is bonded on the backside of the p-doped silicon wafer forms the gate electrode.

5

The field effect transistor produces the current-voltage characteristics shown in Figure 10. It is shown that CPC forms a typical p-channel transistor operating in two different modes, which are the linear regime where the current follows Ohm's law at low source-drain voltage and the saturation regime as the source-drain voltage increase. In the conditions described above, CPC shows a high mobility of $2.5 \times 10^{-1} \text{ cm}^2/\text{V}$ and a high $I_{\text{on}}/I_{\text{off}}$ ratio of 10^6 .

10

THIRD EXAMPLE

15

In a third embodiment of the invention as shown in Figure 12, an OLED was fabricated consisting of; an Indium Tin Oxide transparent conductive anode on a glass substrate, a thin PCVDPAP layer as emitter, and a Ca cathode. The Indium Tin Oxide coated glass ($5 \times 5 \text{ cm}^2$) with a sheet resistance of 15 ohm/sq is patterned using photolithography techniques to produce ten segments each with an active area of $5 \times 6 \text{ mm}^2$. Prior to use, the substrates are cleaned sequentially with detergent, deionized water, acetone, ultrasonicated isopropanol at 60°C , and UV/ozone cleaner for 10 min. The polymeric PCVDPAP material is solubilized in chloroform, filtered through a 0,2 μm PTFE filter, spin-coated at 2000 rpm for 60 s onto the Indium Tin Oxide substrate, and dried at 40°C for 10 min. The Ca layer is thermally evaporated at a pressure of 1×10^{-7} torr and at room temperature.

The OLED produced the electroluminescence spectrum shown in Figure 13. The resulting diode emitted orange-red light with peak emission around 660 nm. No emission of an excimer is observed (no emission peak at higher wavelengths).

5 The current-voltage (curve 1) and luminescence-voltage (curve 2) characteristics of the diode are shown in Figure 14. In the device configuration described above, the maximum luminescence value that has been obtained is 150 cd/m² at 18 V with a low turn-on device voltage of 3 V.

FOURTH EXAMPLE

10

In a fourth embodiment of the invention as shown in Figure 15, an OLED was fabricated consisting of an Indium Tin Oxide transparent conductive anode on a glass substrate, a thin PEDOT-PSS layer to promote hole injection, a thin PCCVP layer as emitter, Bu-PBD as the electron transport layer, a thin LiF layer to promote electron injection, and an Al cathode. The Indium Tin Oxide coated glass (5 x 5 cm²) with a sheet resistance of 15 ohm/sq is patterned using photolithography techniques to produce ten segments each with an active area of 5 x 6 mm². Prior to use, the substrates are cleaned sequentially with detergent, deionized water, acetone, ultrasonicated isopropanol at 60°C, and UV/ozone cleaner for 10 min. The thin PEDOT-PSS (Baytron P CH 8000, Bayer/Germany) layer is first applied by spin-coating at 5000 rpm for 60 s from its water solution (2.8 wt %) onto the Indium Tin Oxide substrate, and dried at 120°C for 1 h. The polymeric PCCVP material is solubilized in chloroform, filtered through a 0.2 µm PTFE filter, spin-coated at 2000 rpm for 60 s, and dried at 40°C for 10 min. Bu-PBD, LiF and Al layers are thermally evaporated at a pressure of 1 x 10⁻⁷ torr and at room temperature.

The diode produced the electroluminescence spectrum shown in Figure 16. The resulting diode emitted orange-red light with peak emission around 636 nm.

The electroluminescence is thus originating from PCCVP itself. No emission of an excimer is observed (no emission peak at higher wavelength). The current-voltage (curve 1) and luminescence-voltage (curve 2) characteristics of the diode are shown in Figure 17. In the device configuration described above, the

5 maximum luminescence value that has been obtained is 122 cd/m² at 20 V with a low turn-on device voltage of 3 V.

FIFTH EXAMPLE

10 In a fifth embodiment of the invention shown in Figure 18, an OPC was fabricated consisting of an Indium Tin Oxide transparent conductive anode on a glass substrate, a blend of PCVDPATA and PTD (20:80) as the absorbing and transporting layer, and an Al cathode. The Indium Tin Oxide coated glass (25 x 25 mm²) with a sheet resistance of 20 ohms/sq is patterned using

15 photolithography techniques to produce one segment with active area of 10 mm². Prior to use, the substrates were cleaned sequentially with detergent, deionized water, acetone and ultrasonicated isopropanol. The PCVDPATA: PTD (20:80) blend is solubilized in chloroform, filtered through a 0,2 µm PTFE filter and spin-coated at 2000 rpm for 60 s. An Al layer was thermally evaporated at a pressure of 1 x 10⁻⁶ torr at room temperature.

20

The photovoltaic cell produced the current-voltage characteristics in dark and under illumination shown in Figure 19.

25 **SIXTH EXAMPLE**

In a sixth embodiment of the invention shown in Figure 20, an OPC was fabricated consisting of an Indium Tin Oxide transparent conductive anode on a glass substrate, a thin PEDOT-PSS layer to promote hole injection, a blend of

PPCVT and PCBM (20:80) as the absorbing and transporting layer, and an Al cathode. The Indium Tin Oxide coated glass (25 x 25 mm²) with a sheet resistance of 20 ohms/sq is patterned using photolithography techniques to produce one segment with active area of 10 mm². Prior to use, the substrates 5 were cleaned sequentially with detergent, deionized water, acetone and ultrasonicated isopropanol. The PPCVT: PCBM (20:80) blend is solubilized in chloroform, filtered through a 0,2 µm PTFE filter and spin-coated at 2000 rpm for 60 s. An Al layer was thermally evaporated at a pressure of 1 x 10⁻⁶ torr at room temperature.

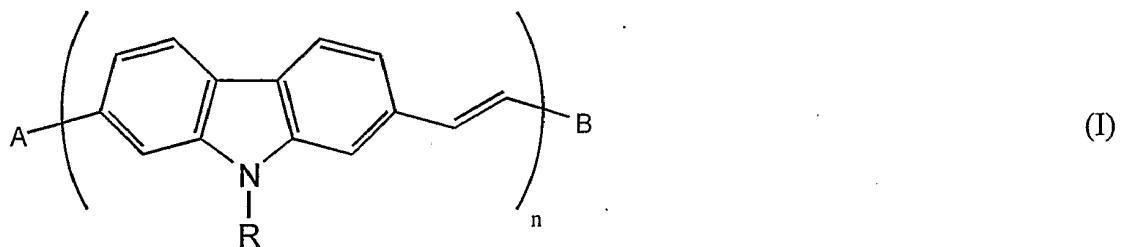
10

The photovoltaic cell produced the current-voltage characteristics in dark and under illumination shown in Figure 21.

It will be appreciated that, in light of the disclosure herein, one skilled in the art 15 could employ the method disclosed herein to produce OLEDs and related devices from carbazolene derivatives in addition to the 2,7 derivatives described in the examples herein.

There follows a summary of embodiments contemplated by the present 20 invention. It is to be understood, however, that these are intended as being representations and in no way limiting the full scope of the invention.

In one embodiment of the invention there is provided an Organic Field Effect Transistor (OFET), an Organic Light Emitting Diode (OLED), and an Organic 25 Photovoltaic Cell (OPC) comprising active material including a conjugated oligomeric or polymeric 2,7-carbazolenevinylene derivative described by the formula (I):

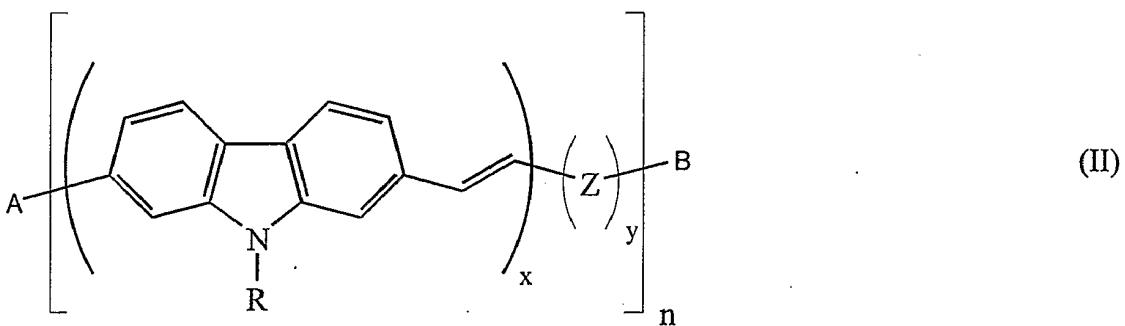


wherein n is an integer ≥ 3 , R represents a substituent that is a hydrogen, or linear or branched alkyl group containing 1 to 20 carbon atoms, linear or

5 branched alkoxy group containing 1 to 20 carbon atoms, poly (ethyleneoxy), cyano, aryl group, amide group or benzoyl group, and A , B are any type of end-cap groups selected from the group consisting of hydrogen, linear or branched alkyl group containing 1 to 20 carbon atoms, linear or branched alkoxy group containing 1 to 20 carbon atoms, cyano group, halogen group, monovalent
10 aromatic group, and monovalent aromatic complex ring group having one nitrogen atom as a hetero-atom.

In another embodiment of the invention there is provided an Organic Field Effect Transistor (OFET), an Organic Light Emitting Diode (OLED), and an Organic

15 Photovoltaic Cell (OPC) comprising active material including a conjugated 2,7-carbazolenevinylene derivative where 2,7-carbazolenevinylene monomers can also be alternated with other monomers to form oligomeric or polymeric materials according to the general formula (II):



20

wherein n is an integer ≥ 3 , R represents a substituent that is a hydrogen, or linear or branched alkyl group containing 1 to 20 carbon atoms, linear or branched alkoxy group containing 1 to 20 carbon atoms, poly (ethyleneoxy), cyano, aryl, amide or benzoyl, x is an integer between 1 to 1000, y is an integer 5 between 0 to 1000, Z is any type of comonomer selected from the group consisting of ethylene, acetylene, C₆-C₂₂ mononuclear/polynuclear aromatic, C₂-C₁₀ mononuclear/polynuclear heterocyclic groups and tertiary arylamines, and A, B are any type of end-cap groups selected from the group consisting of hydrogen, linear or branched alkyl group containing 1 to 20 carbon atoms, linear 10 or branched alkoxy group containing 1 to 20 carbon atoms, cyano group, halogen group, monovalent aromatic group, and monovalent aromatic complex ring group having one nitrogen atom as a hetero-atom.

In a further embodiment of the invention there is provided an OFET, wherein 15 said 2,7-carbazolenevinylene derivative is 1,4-bis(vinylene-(N-methyl-7-hexyl-2-carbazole))phenylene (RCPCR).

In a further embodiment of the invention there is provided an OFET, wherein 20 said 2,7-carbazolenevinylene derivative is 1,4-bis(vinylene-(N-hexyl-2-carbazole))phenylene (CPC).

In a still further embodiment of the invention there is provided an OLED, wherein said 2,7-carbazolenevinylene derivative is [Poly (N-(2-ethylhexyl-2,7-carbazolenecyanovinylene-co-2,5-bis(diphenylamine)-1,4-phenylenecyanovinylene-co-2,5-dioctyloxy-1,4-phenylenecyanovinylene)] 25 (PCVDPAP).

In a still further embodiment of the invention there is provided an OLED, wherein said 2,7-carbazolenevinylene derivative is [Poly (N-(2-ethylhexyl)-2,7-carbazolenecyanovinylene-*alt*-2,5-dioctyloxy-1,4-phenylenevinylene)] (PCCVP).

5 In a still further embodiment of the invention there is provided an OLED, wherein said 2,7-carbazolenevinylene derivative is mixed with a second active material.

In a still further embodiment of the invention there is provided an OLED

10 comprising a hole transport layer, an electron transport layer, and wherein at least one of said hole transport layer and said electron transport layer comprises either alone or in combination as active material a conjugated 2,7-carbazolenevinylene derivative.

15 In a still further embodiment of the invention there is provided an OLED, further comprising a carrier promotion layer adjacent at least one of said electron transport layer and said hole transport layer.

In a still further embodiment of the invention there is provided an OLED,

20 wherein said electron promotion is LiF.

In a still further embodiment of the invention there is provided an OLED, wherein said hole promotion is [Poly (ethylene dioxythiophene: polystyrene sulfonate)] (PEDOT-PSS).

25

In yet another embodiment of the invention there is provided an OLED, wherein said hole promotion is [Poly (ethylene dioxythiophene: polystyrene sulfonate)] (PEDOT-PSS), said hole transport is [Poly (N-(2-ethylhexyl)-2,7-carbazolenecyanovinylene-*alt*-2,5-dioctyloxy-1,4-phenylenevinylene)] (PCCVP),

said electron transport layer is Bu-PBD (2-(4-biphenylyl)-5-(4-tert-butylphenyl)-1,3,4-oxadiazole) and said electron promotion is LiF.

In another embodiment of the invention there is provided an OPC, wherein said

5 2,7-carbazolenevinylene derivative is [Poly (N-(2-ethylhexyl-2,7-carbazolenevinylene-co-2,5-bis(diphenylamine)-1,4-phenylenevinylene-co-((4-(2-ethylhexyloxy)-phenyl)-bis-(4'-phenylene)amine)] (PCVDPATA).

In another embodiment of the invention there is provided an OPC, wherein said

10 2,7-carbazolenevinylene derivative is [Poly (N-(4-hexyloxyphenyl)-2,7-carbazolenevinylene-alt-(3-hexyl-2,5-thiophenevinylene))] (PPCVT).

In another embodiment of the invention there is provided an OPC, wherein said 15 2,7-carbazolenevinylene derivative is mixed with a second active material.

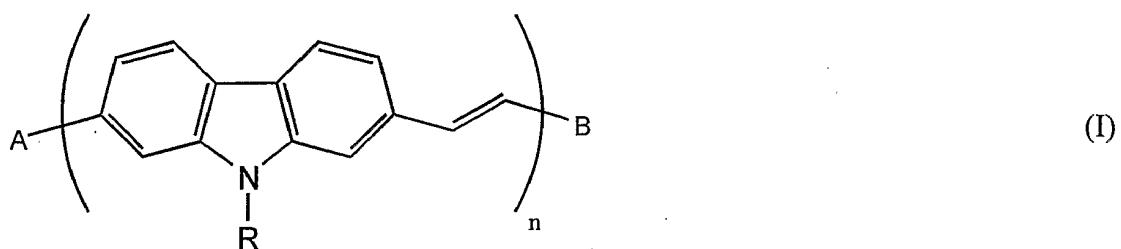
In another embodiment of the invention there is provided an OPC, wherein said second active material is [N,N'-Bis(2,6-dimethylphenyl)-3,4,9,10-
20 perylenetetracarboxylic diimide] (PTD).

25 In another embodiment of the invention there is provided an OPC, wherein said second active material is [6,6-phenyl-C61 butyric acid methyl ester] (PCBM).

In another embodiment of the invention there is provide an OPC comprising a
hole tranport layer, an electron transport layer, and wherein at least one of said
20 hole transport layer and said electron transport layer comprises either alone or in
combination as active material a conjugated 2,7-carbazolenevinylene derivative.

Claims:

1. An organic based electronic device having as an active material a conjugated oligomeric or polymeric 2,7-carbazolenevinylene derivative described by the formula (I):

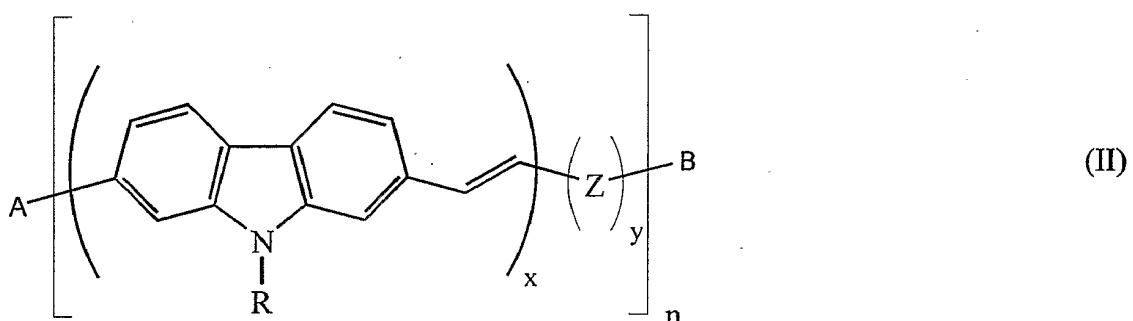


wherein n is an integer ≥ 3 , R represents a substituent that is a hydrogen, or linear or branched alkyl group containing 1 to 20 carbon atoms, linear or branched alkoxy group containing 1 to 20 carbon atoms, poly (ethyleneoxy), cyano, aryl group, amide group or benzoyl group, and A, B are any type of end-cap groups selected from the group consisting of hydrogen, linear or branched alkyl group containing 1 to 20 carbon atoms, linear or branched alkoxy group containing 1 to 20 carbon atoms, cyano group, halogen group, monovalent aromatic group, and monovalent aromatic complex ring group having one nitrogen atom as a hetero-atom.

2. The organic based device as defined in claim 1 being an Organic Field Effect Transistor (OFET).
3. The organic based device as defined in claim 1 being an Organic Light Emitting Diode (OLED).

4. The organic based device as defined in claim 1 being an Organic Photovoltaic Cell (OPC).

5. An organic based device from the group; an Organic Field Effect Transistor (OFET), an Organic Light Emitting Diode (OLED), and an Organic Photovoltaic Cell (OPC), the device comprising active material including a conjugated 2,7-carbazolenevinylene derivative where 2,7-carbazolenevinylene monomers can also be alternated with other monomers to form oligomeric or polymeric materials according to the general formula (II):



wherein n is an integer ≥ 3 , R represents a substituent that is a hydrogen, or linear or branched alkyl group containing 1 to 20 carbon atoms, linear or branched alkoxy group containing 1 to 20 carbon atoms, poly (ethyleneoxy), cyano, aryl, amide or benzoyl, x is an integer between 1 to 1000, y is an integer between 0 to 1000, Z is any type of comonomer selected from the group consisting of ethylene, acetylene, C₆-C₂₂ mononuclear/polynuclear aromatic, C₂-C₁₀ mononuclear/polynuclear heterocyclic groups and tertiary arylamines, and A, B are any type of end-cap groups selected from the group consisting of hydrogen, linear or branched alkyl group containing 1 to 20 carbon atoms, linear or branched alkoxy group containing 1 to 20 carbon atoms, cyano group, halogen group, monovalent aromatic group, and monovalent aromatic complex ring group having one nitrogen atom as a hetero-atom.

6. The organic based device of claim 5 being an OFET, wherein said 2,7-carbazolenevinylene derivative is 1,4-bis(vinylene-(N-methyl-7-hexyl-2-carbazole))phenylene (RCPCR).
7. The organic based device of claim 5 being an OFET, wherein said 2,7-carbazolenevinylene derivative is 1,4-bis(vinylene-(N-hexyl-2-carbazole))phenylene (CPC).
8. The organic based device of claim 5 being an OLED, wherein said 2,7-carbazolenevinylene derivative is [Poly (N-(2-ethylhexyl)-2,7-carbazolenecyanovinylene-co-2,5-bis(diphenylamine)-1,4-phenylenecyanovinylene-co-2,5-dioctyloxy-1,4-phenylenecyanovinylene)] (PCVDPAP).
9. The organic based device of claim 5 being an OLED, wherein said 2,7-carbazolenevinylene derivative is [Poly (N-(2-ethylhexyl)-2,7-carbazolenecyanovinylene-*alt*-2,5-dioctyloxy-1,4-phenylenevinylene)] (PCCVP).
10. The organic based device of claim 5 being an OLED, wherein said 2,7-carbazolenevinylene derivative is mixed with a second active material.
11. The organic based device of claim 5 being an OLED comprising a hole transport layer, an electron transport layer, and wherein at least one of said hole transport layer and said electron transport layer comprises either alone or in combination as active material a conjugated 2,7-carbazolenevinylene derivative.
12. The organic based device of claim 5 being an OLED, further comprising a carrier promotion layer adjacent at least one of said electron transport layer and said hole transport layer.

13. The organic based device of claim 5 being an OLED, wherein said electron promotion is LiF.
14. The organic based device of claim 5 being an OLED, wherein said hole promotion is [Poly (ethylene dioxythiophene: polystyrene sulfonate)] (PEDOT-PSS).
15. The organic based device of claim 5 being an OLED, wherein said hole promotion is [Poly (ethylene dioxythiophene: polystyrene sulfonate)] (PEDOT-PSS), said hole transport is [Poly (N-(2-ethylhexyl)-2,7-carbazolenecyanovinylene-*alt*-2,5-dioctyloxy-1,4-phenylenevinylene)] (PCCVP), said electron transport layer is Bu-PBD (2-(4-biphenylyl)-5-(4-tert-butylphenyl)-1,3,4-oxadiazole) and said electron promotion is LiF.
16. The organic based device of claim 5 being an OPC, wherein said 2,7-carbazolenevinylene derivative is [Poly (N-(2-ethylhexyl)-2,7-carbazolenevinylene-co-2,5-bis(diphenylamine)-1,4-phenylenevinylene-co-((4-(2-ethylhexyloxy)-phenyl)-bis-(4'-phenylene)amine)] (PCVDPATA).
17. The organic based device of claim 5 being an OPC, wherein said 2,7-carbazolenevinylene derivative is [Poly (N-(4-hexyloxyphenyl)-2,7-carbazolenevinylene-*alt*-(3-hexyl-2,5-thiophenevinylene))] (PPCVT).
18. The organic based device of claim 5 being an OPC, wherein said 2,7-carbazolenevinylene derivative is mixed with a second active material.

19. The organic based device of claim 5 being an OPC, wherein said second active material is [N,N'-Bis(2,6-dimethylphenyl)-3,4,9,10-perylenetetracarboxylic diimide] (PTD).
20. The organic based device of claim 5 being an OPC, wherein said second active material is [6,6-phenyl-C61 butyric acid methyl ester] (PCBM).
21. The organic based device of claim 5 being an OPC comprising a hole transport layer, an electron transport layer, and wherein at least one of said hole transport layer and said electron transport layer comprises either alone or in combination as active material a conjugated 2,7-carbazolenevinylene derivative.

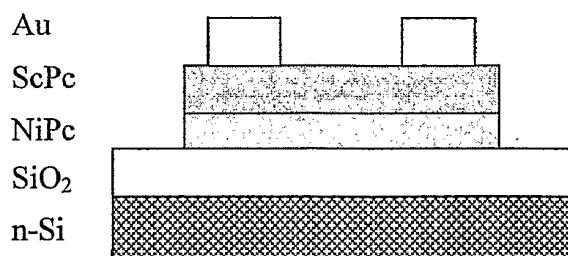


Figure 1 (prior art)

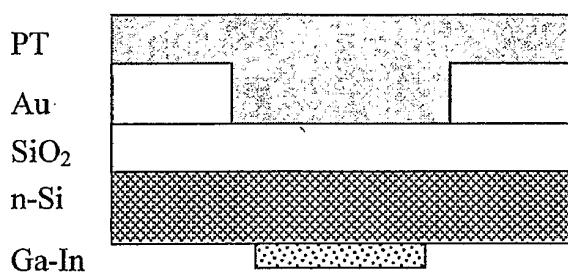


Figure 2 (prior art)

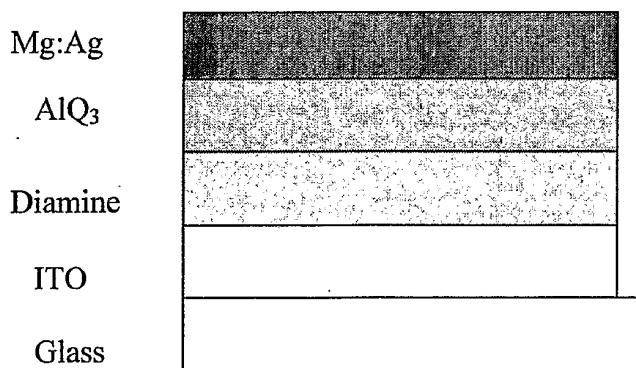


Figure 3 (prior art)

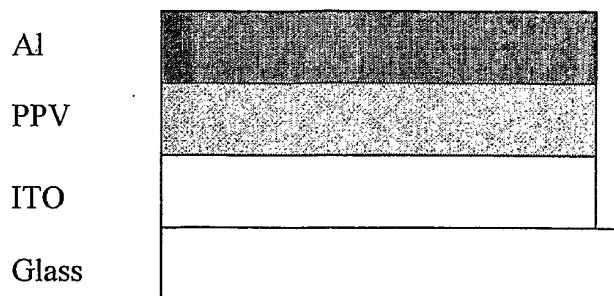


Figure 4 (prior art)

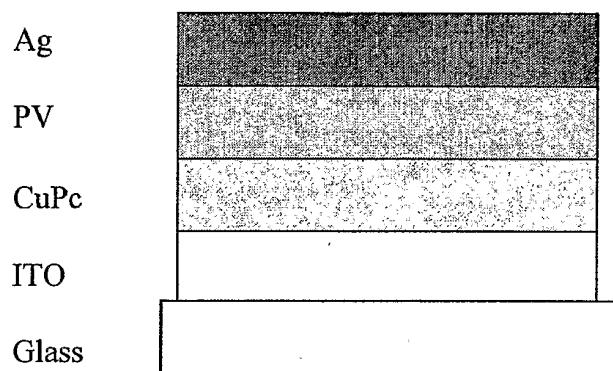


Figure 5 (prior art)

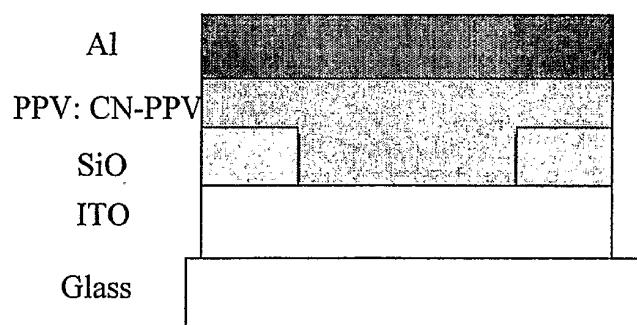
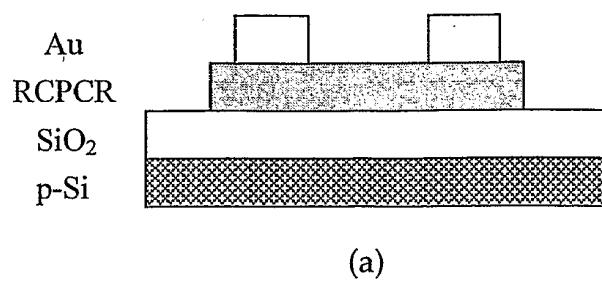
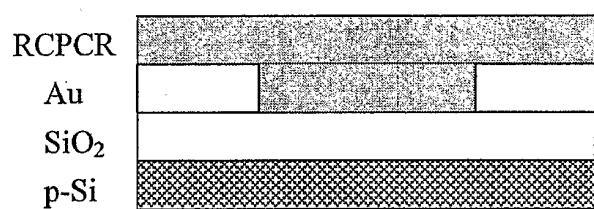


Figure 6 (prior art)



(a)

Figure 7 (a)



(b)

Figure 7 (b)

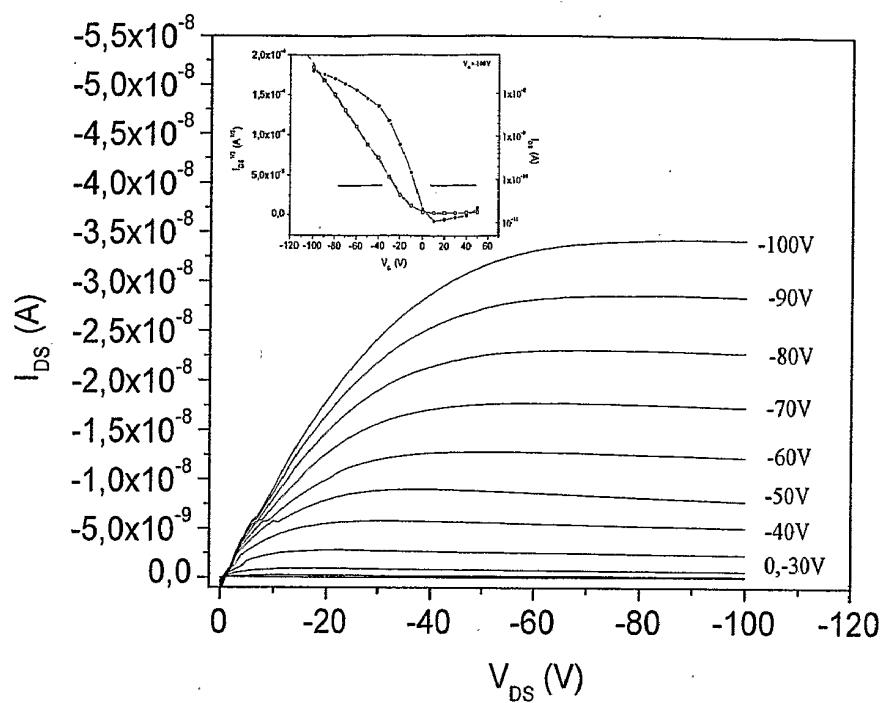
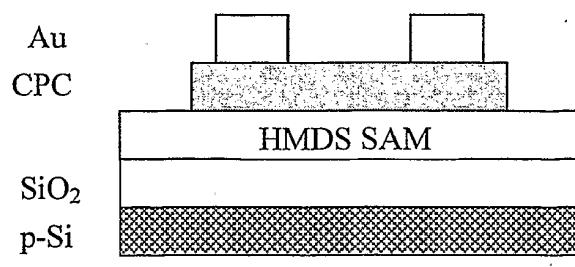
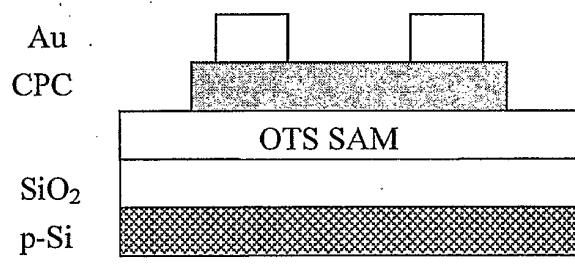


Figure 8



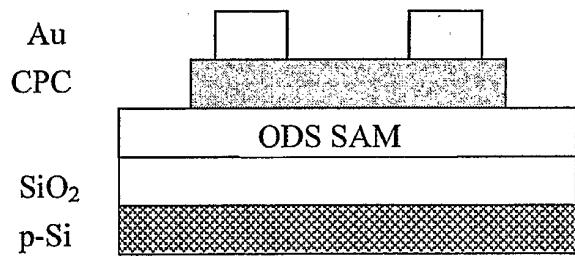
(a)

Figure 9 (a)



(b)

Figure 9 (b)



(c)

Figure 9 (c)

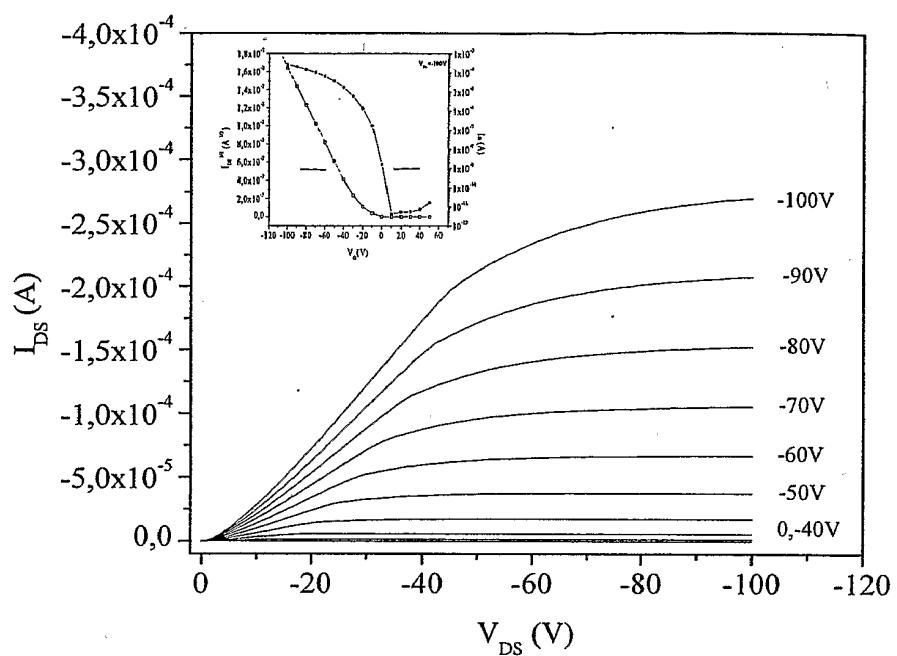


Figure 10

	plain		hmnds		ots		ods	
T _{dep} °C	μ cm ² /V.s	I _{on} /I _{off}	μ cm ² /V.s	I _{on} /I _{off}	μ cm ² /V.s	I _{on} /I _{off}	μ cm ² /V.s	I _{on} /I _{off}
25	1.2x10 ⁻³	10 ⁵	2.7x10 ⁻²	10 ⁶	7.2x10 ⁻²	10 ⁶	1.8x10 ⁻²	10 ⁶
75	4.6x10 ⁻²	10 ⁶	2.5x10 ⁻¹	10 ⁶	4.4x10 ⁻²	10 ⁶	1.1x10 ⁻²	10 ⁶
125	1.3x10 ⁻²	10 ⁶	9.1x10 ⁻²	10 ⁶	4.6x10 ⁻²	10 ⁶	9.7x10 ⁻²	10 ⁶

Figure 11

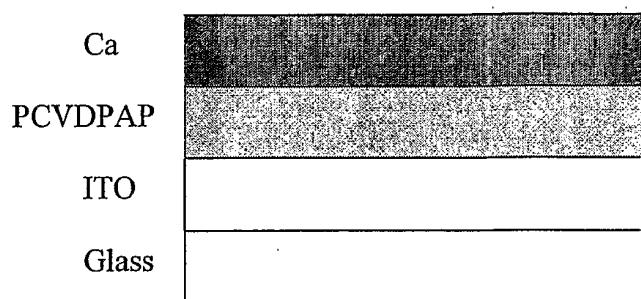


Figure 12

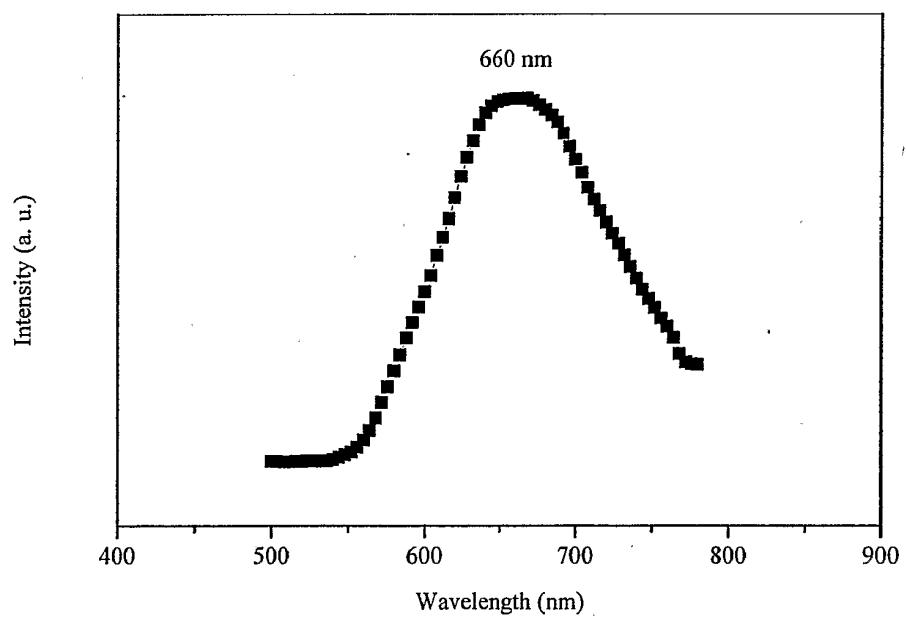


Figure 13

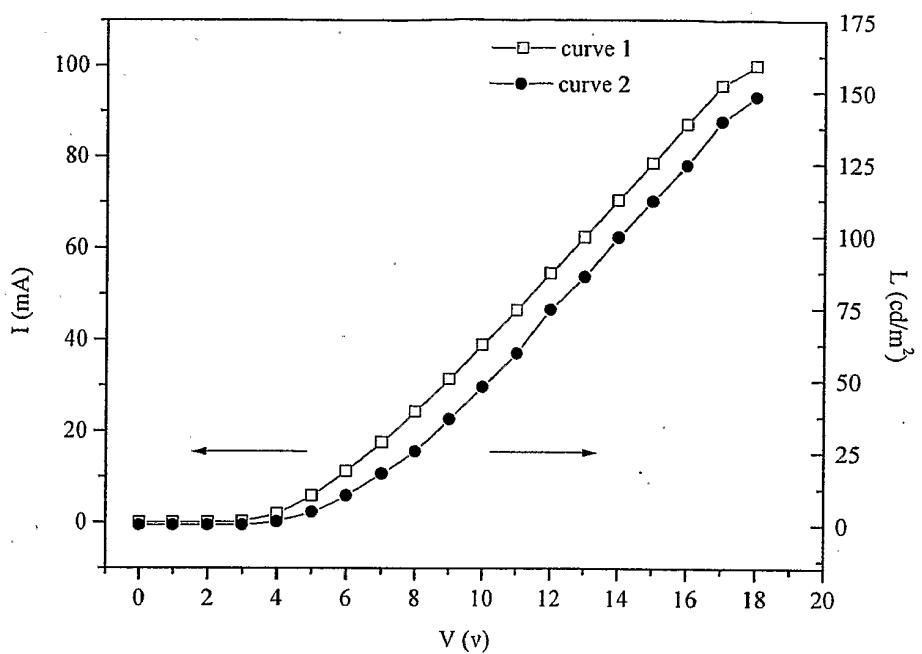


Figure 14

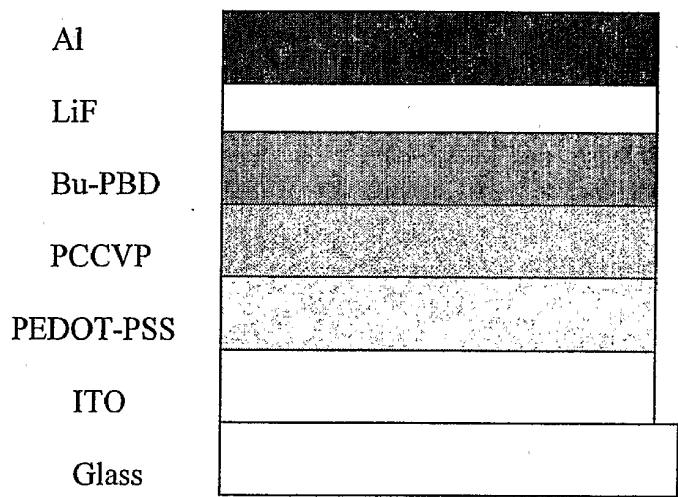


Figure 15

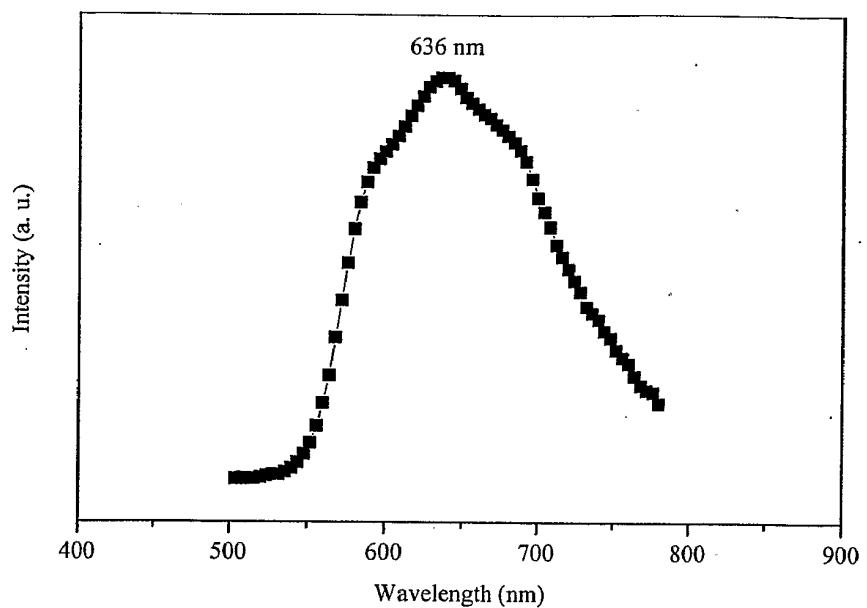


Figure 16

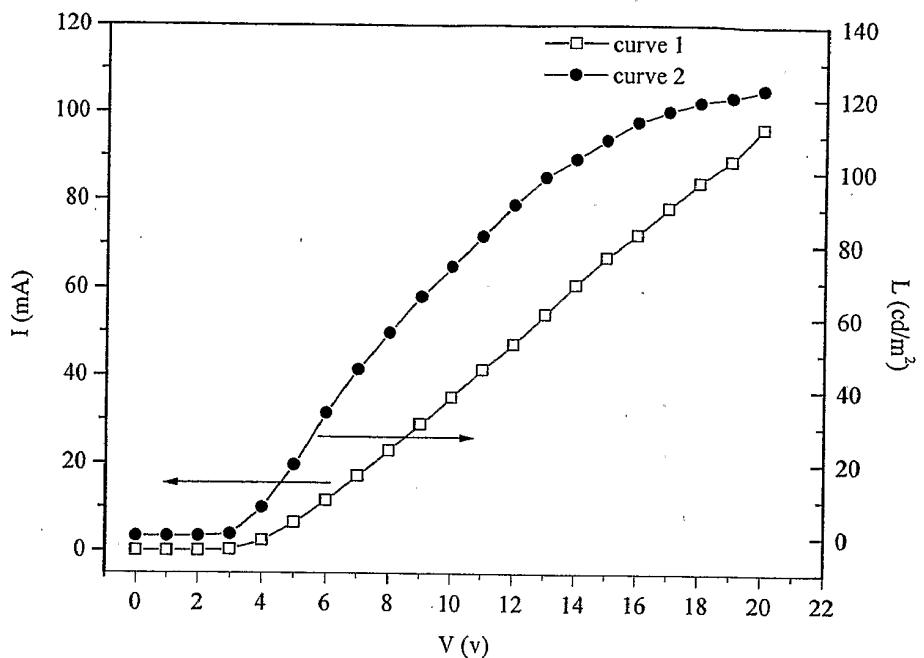


Figure 17

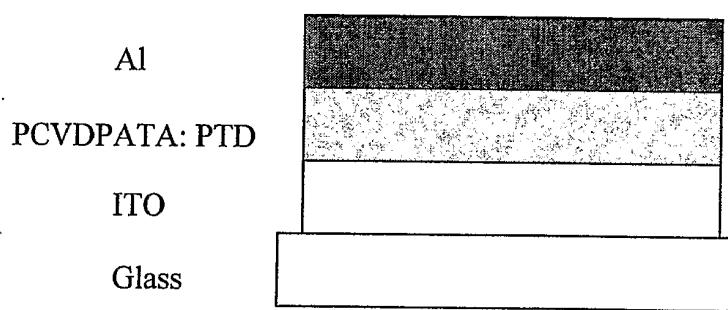


Figure 18

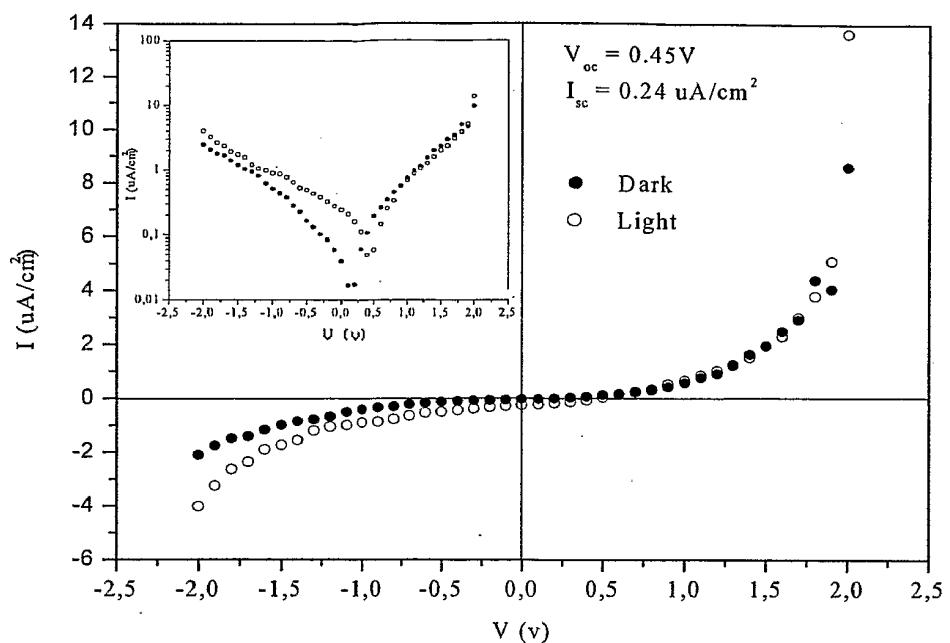


Figure 19

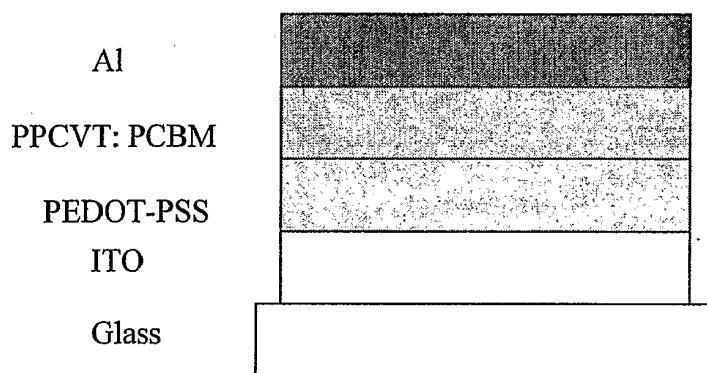


Figure 20

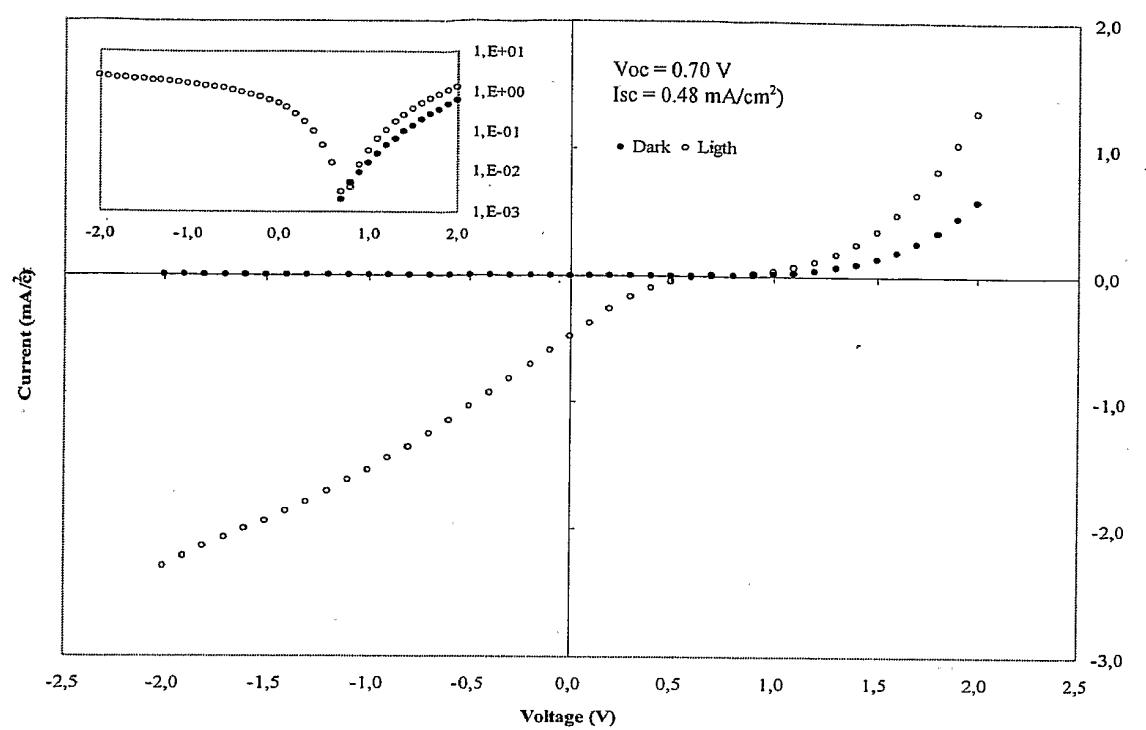


Figure 21

INTERNATIONAL SEARCH REPORT

International application No.
PCT/CA2004/001755

A. CLASSIFICATION OF SUBJECT MATTER

IPC⁷ H01L 51/30, C08F 12/32, C08F 26/12, C08J 5/20, H01L 51/20

B. FIELDS SEARCHED

Minimum documentation searched (classification system followed by classification symbols)

Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched
IPC⁰⁷ H01L, C08J, C08F

Electronic data base consulted during the international search (name of data base, and, where practicable, search terms used)
CANADIAN PATENT DATABASE, STN-CAPLUS, ACS PUB, WEST STATION, DELPHION, PLUSPAT.

C. DOCUMENTS CONSIDERED TO BE RELEVANT

Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
X	US A1 2003/0008172, (LECLERC, M. et al.) 2003.01.09, paragraphs [14]-[16].	1-3, 5-13
Y	US A 6, 111, 063 (JONG-WOOK PARK, S. et al.) 2000.08.29, whole document.	1, 2, 3, 5
Y	JP A 2002-09 3582 (ZHENG, S. et al.) 2002.03.29, formula 22.	5, 21
Y	Brabec, C. J., Sariciftci, N. S., and Hummelen, J. C. 'Plastic Solar Cells' Adv. Funct. Mater. 2001, 11(1), pages 15-26. whole document.	16
A	Nature (BURROUGHES, J. H. et al.) 1990.11.11, Vol. 347, pages 539-541.	1, 5

Further documents are listed in the continuation of Box C.

Patent family members are listed in annex. X

* Special categories of cited documents :	
"A" document defining the general state of the art which is not considered to be of particular relevance	"T" later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the invention
"E" earlier application or patent but published on or after the international filing date	"X" document of particular relevance; the claimed invention cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone
"L" document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified)	"Y" document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such documents, such combination being obvious to a person skilled in the art
"O" document referring to an oral disclosure, use, exhibition or other means	
"P" document published prior to the international filing date but later than the priority date claimed	"&" document member of the same patent family

Date of the actual completion of the international-type search
30 December 2004 (30-12-2004)

Date of mailing of the international-type search report
16 February 2005 (16-02-2005)

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INTERNATIONAL SEARCH REPORT
Information on patent family members

International application No.
PCT/CA2004/001755

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专利名称(译)	2,7-咔唑亚乙烯基衍生物作为生产有机基电子器件的新材料		
公开(公告)号	EP1668719A4	公开(公告)日	2009-08-26
申请号	EP2004786673	申请日	2004-09-29
[标]申请(专利权)人(译)	加拿大国家研究委员会		
申请(专利权)人(译)	加拿大国家研究委员会的		
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IPC分类号	H01L51/30 C08F12/32 C08F26/12 C08J5/20 C08G61/12 H01L51/00 H01L51/40 H01L51/50		
CPC分类号	H01L51/0043 B82Y10/00 C08G61/124 C08G73/0672 H01L51/0012 H01L51/0035 H01L51/0037 H01L51/0038 H01L51/0059 H01L51/0072 H01L51/0525 H01L51/0545 H01L51/0558 H01L51/42 H01L51/4253 H01L51/5012 H01L51/5048 Y02E10/549		
代理机构(译)	哈丁RICHARD PATRICK		
优先权	60/507506 2003-10-02 US		
其他公开文献	EP1668719A1		
外部链接	Espacenet		

摘要(译)

有机场效应晶体管 (OFET) , 有机发光二极管 (OLED) , 和有机光伏电池 (OPC) , 包括作为活性材料的式 (I) 所示的共轭低聚或聚合2,7-咔唑亚乙烯基衍生物或 (II) : 这种OFET , OLED和OPC具有改进的器件性能和效率。

